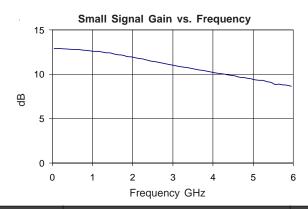


Product Description

The SGA-0163 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high FT and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.

The matte tin finish on Sirenza's lead-free package utilizes a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. This package is also manufactured with green molding compounds that contain no antimony trioxide nor halogenated fire retardants.



SGA-0163

SGA-0163Z (Pro) RoHS Compliant & Green Package



DC-4500 MHz, Silicon Germanium Cascadeable **Gain Block**



Product Features

- Now available in Lead Free, RoHS Compliant, & Green Packaging
- DC-4500 MHz Operation
- Single Voltage Supply
- Low Current Draw: 8mA at 2.1V typ.
- High Output Intercept: 10 dBm typ. at 1900 MHz

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- · Wireless Data, Satellite

Symbol	Parameter	Frequency	Units	Min.	Тур.	Max.
P _{1dB}	Output Power at 1dB Compression	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm		-1.8 -1.8 -2.4	
IP ₃	Third Order Intercept Point	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm		9.4 9.8 9.2	
S ₂₁	Small Signal Gain	850 MHz 1950 MHz 2400 MHz	dB dB dB		12.7 12.0 11.6	
BW _{3dB}	3dB Bandwidth		MHz		4500	
VSWR _{IN}	Input VSWR	DC - 4500MHz	-		1.6:1	
VSWR _{OUT}	Output VSWR	DC - 4500MHz	-		1.3:1	
S ₁₂	Reverse Isolation	850 MHz 1950 MHz 2400 MHz	dB dB dB		17.6 18.1 18.3	
NF	Noise Figure	1950 MHz	dB		4.6	
V _D	Device Operating Voltage		V		2.1	
I _D	Device Operating Current		mA	6	8	10
R _{TH} , j-l	Thermal Resistance (junction - lead)		°C/W		255	
Test Conditions: $V_s = 5 \text{ V}$ $I_D = 5 \text{ mA Typ.}$ OIP ₃ Tone Spacing = 1 MHz, Pout per tone = -17 dBm					out per tone = -1	7 dBm

 $R_{BIAS} = 360 \text{ Ohms}$ $T_1 = 25^{\circ}C$ $Z_s = Z_l = 50 \text{ Ohms}$

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Test Conditions:



Key parameters, at typical operating frequencies:

to, parameters, at typical operating requestions.					
	Typical		Test Condition		
Parameter	25°C	Unit	$(I_D = 8mA, unless otherwise noted)$		
100 MHz					
Gain	12.9	dB			
Output IP3	9.4	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-1.5	dBm			
Input Return Loss	12.5	dB			
Reverse Isolation	17.3	dB			
Noise Figure	4.6	dB	$Z_s = 50 \text{ Ohms}$		
500 MHz					
Gain	12.8	dB			
Output IP3	9.5	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-1.5	dBm			
Input Return Loss	12.7	dB			
Reverse Isolation	17.4	dB			
Noise Figure	4.6	dB	$Z_s = 50 \text{ Ohms}$		
850 MHz					
Gain	12.7	dB			
Output IP3	9.4	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-1.8	dBm			
Input Return Loss	12.8	dB			
Reverse Isolation	17.6	dB			
Noise Figure	4.7	dB	$Z_s = 50 \text{ Ohms}$		
1950 MHz					
Gain	12.0	dB			
Output IP3	9.8	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-1.8	dBm			
Input Return Loss	12.4	dB			
Reverse Isolation	18.1	dB			
Noise Figure	4.6	dB	$Z_s = 50 \text{ Ohms}$		
2400 MHz					
Gain	11.6	dB			
Output IP3	9.2	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-2.5	dBm			
Input Return Loss	12.1	dB			
Reverse Isolation	18.3	dB			
3500 MHz					
Gain	10.6	dB			
Output IP3	9.3	dBm	Tone spacing = 1 MHz, Pout per tone = -17dBm		
Output P1dB	-2.7	dBm			
Input Return Loss	11.8	dB			
Reverse Isolation	18.5	dB			

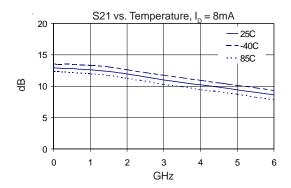
Absolute Maximum Ratings

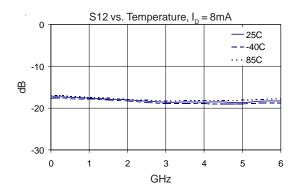
Parameter	Absolute Limit	
Max. Device Current (I _D)	16 mA	
Max. Device Voltage (V _D)	6 V	
Max. RF Input Power	-4 dBm	
Max. Junction Temp. (T _J)	+150°C	
Operating Temp. Range (T _L)	-40°C to +85°C	
Max. Storage Temp.	+150°C	

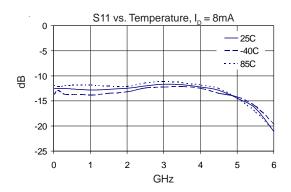
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

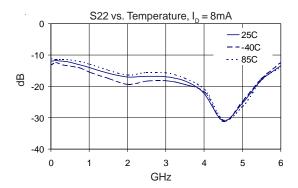
Bias conditions should also satisfy the following expression: $I_{_D}V_{_D}<(T_{_J}-T_{_L})\ /\ R_{_{TH^1}}\ j\text{-}I$

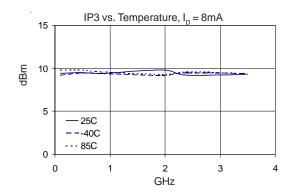


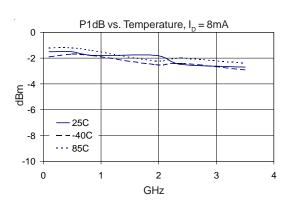






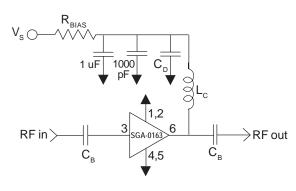


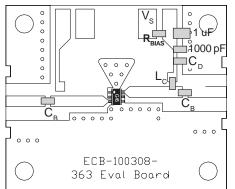






Basic Application Circuit





Application Circuit Element Values

Reference	Frequency (Mhz)				
Designator	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _c	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_D =8mA R_{BIAS} =(V_S - V_D) / I_D					
Supply Voltage(V _s)	5 V	7.5 V	9 V	12 V	
R _{BIAS} 360 Ω 680 Ω 820 Ω 1.2K Ω					
Note: R _{BIAS} provides DC bias stability over temperature.					

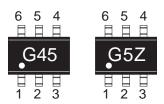
Mounting Instructions

- 1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin#	Function	Description
3	RF IN	RF input pin. This pin requires the use o an external DC blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
6	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

Part Number	Reel Size	Devices/Reel	
SGA-0163	7"	3000	
SGA-0163Z	7"	3000	

Part Identification Marking



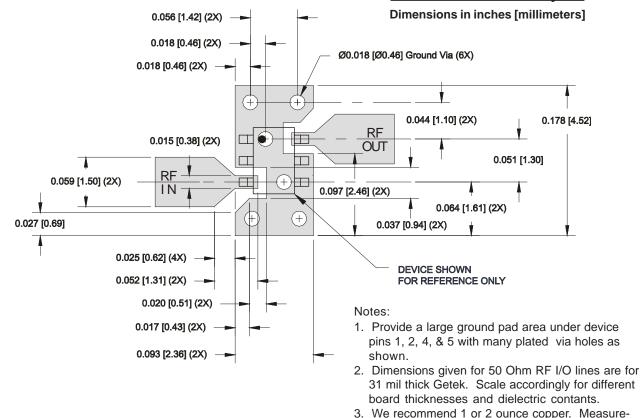


Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.



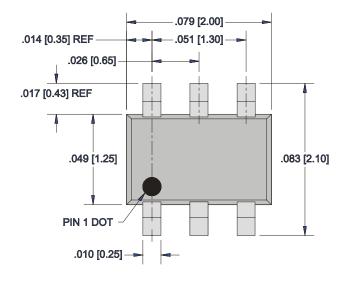
SOT-363 PCB Pad Layout

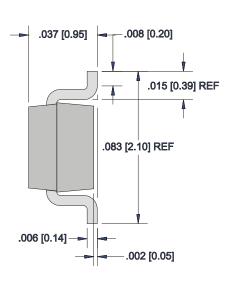


SOT-363 Nominal Package Dimensions

Dimensions in inches [millimeters]

A link to the SOT-363 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.





ments for this data sheet were made on a 31 mil thick Getek with 1 ounce copper on both sides.